Erratum: Anomalous strong repulsive step-step interaction on slightly misoriented Si(113) **[Phys. Rev. B 55, 7864 (1997)]**

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Figure 1(a) of the above mentioned paper is missing. The correct Fig. 1 is displayed below. The figure caption of Fig. 1 remains unaltered.

FIG. 1. (a) The Si(113)-3×2 reconstruction model given by Dabrowski, Müssig, and Wolff (Ref. 4). The surface unit cell, indicated by the dashed lines, contains atoms which are terminated like atoms of the (001) surface (labeled 2 and 3) and atoms which are terminated like atoms of the (111) surface (labeled 1 and 4). The length $a_{\perp}$ and width $a_{\parallel}$ of the unit cell are 12.76 Å and 11.54 Å, respectively. (b) High-resolution STM image (scan size 5×3.5 nm²) of the Si(113)3×2 surface. The sample bias is −2 V and the tunneling current is 1 nA. The dimer bond between atoms 2 and 3 as well as the filled dimer bonds of atoms 1 and 4 are labeled in the figure.